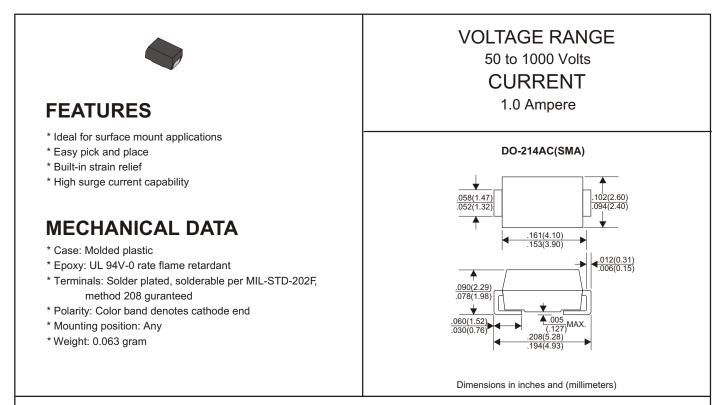


M1 THRU M7 1.0 AMP SURFACE MOUNT SILICON RECTIFIERS



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature uniess otherwies specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

TYPE NUMBER	M1	M2	M3	M4	M5	M6	M7	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current			•	•	•	•		
.375"(9.5mm) Lead Length at Ta=75 [°] C		1.0						
Peak Forward Surge Current, 8.3 ms single half sine-wave								
superimposed on rated load (JEDEC method)		30						
Maximum Instantaneous Forward Voltage at 1.0A		1.1					V	
Maximum DC Reverse Current Ta=25°C		5.0						
at Rated DC Blocking Voltage Ta=100°C		50						
Typical Junction Capacitance (Note 1)		15						
Typical Thermal Resistance R JA (Note 2)		50						°C/W
Operating and Storage Temperature Range TJ, Tstg		-65-+150						

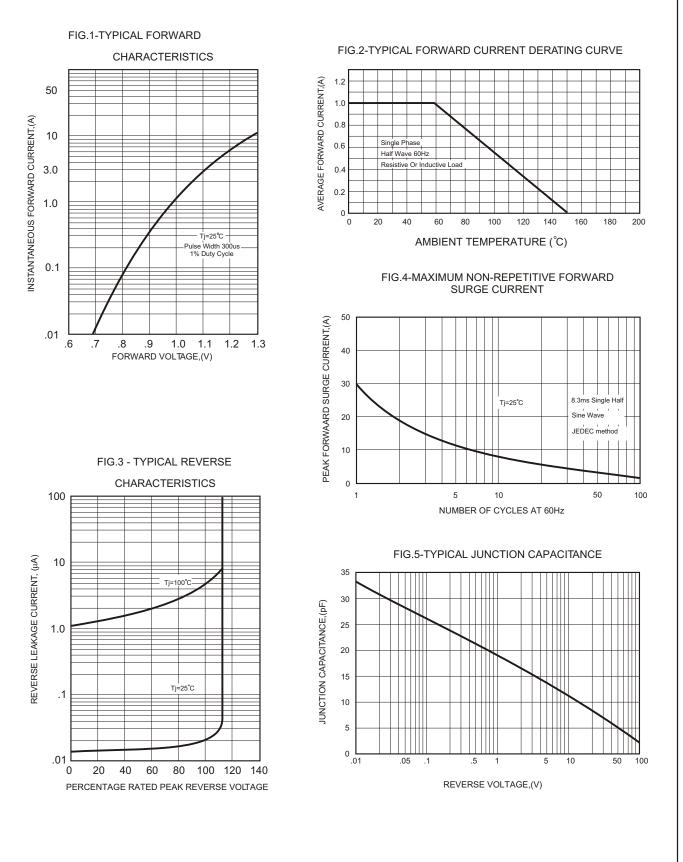
NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal Resistance from Junction to Ambient.



RATING AND CHARACTERISTIC CURVES (M1THRU M7)



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